

Amendments to the Claims:

The following listing of claims will replace all prior versions, and listings, of claims in the application:

1. (Previously Presented) A CVD system provided with a plasma generator comprised of a conductive upper and lower plates and a circumferential wall made of an insulator, having a plasma generation chamber separated from a film deposition chamber in which a substrate is arranged, wherein a material gas is directly supplied into the film deposition chamber, radicals in the plasma are introduced into the film deposition chamber from the plasma generator via through holes of said lower plate that are distributed across said lower plate, and a thin film is deposited on the substrate, said CVD system further comprising:

a cleaning gas feeder provided to said plasma generator,

said lower plate is connected to ground, and

each of said through holes of said lower plate is designed to pass the radicals only to the film deposition chamber,

said lower plate further including a reserve space and a plurality of diffusion holes that are distributed across said lower plate and interspersed with said through holes, whereby a surface area of said lower plate includes an interspersed distribution of both diffusion holes and through holes, and said material gas is directly supplied into the film deposition chamber through said reserve space and said plurality of diffusion holes to react with said radicals supplied through said through holes in the film deposition chamber,

wherein a cleaning gas is introduced through said cleaning gas feeder to produce plasma in the plasma generator and generate radicals, and the radicals are introduced through said through holes to said film deposition chamber to strike the substrate and thereby

clean the substrate and further the film is deposited on the substrate within the same chamber as the substrate is not moved.

2. (Currently Amended) A CVD system as set forth in claim 1, wherein said cleaning gas is a gas selected from O₂, H₂, F₂, N₂, ~~dilute gas~~ noble gas or rare gas, and halide gas or a gas comprised of a suitable mixture of the plural gases.

3-4. (Canceled).

5. (Previously Presented) A CVD system provided with a plasma generator comprised of a conductive upper and lower plates and a circumferential wall made of an insulator, having a plasma generation chamber separated from a film deposition chamber in which a substrate is arranged, wherein a material gas is directly supplied into the film deposition chamber, radicals in the plasma are introduced into the film deposition chamber from the plasma generator via through holes that are distributed across each of said lower plates, and a thin film is deposited on the substrate, said CVD system further comprising:

a cleaning gas feeder provided to said plasma generator, and

a diameter of each of said through holes of said lower plate is designed to pass the radicals only to the film deposition chamber,

said lower plate further including a reserve space and a plurality of diffusion holes that are distributed across each of said lower plates and interspersed with said through holes, whereby a surface area of said lower plates includes an interspersed distribution of both diffusion holes and through holes, and said material gas is directly supplied into the film deposition chamber through said reserve space and said plurality of diffusion holes to react with said radicals supplied through said through holes in the film deposition chamber,

wherein a cleaning gas is introduced through said cleaning gas feeder to produce plasma in the plasma generator and generate radicals, and the radicals are introduced through said through holes to said film deposition chamber to strike the substrate and thereby

- clean the substrate and further the film is deposited on the substrate within the same chamber as the substrate is not moved.

6. (Previously Presented) A CVD system as set forth in ~~claim 1~~claim 5, wherein said cleaning gas is a gas selected from the group consisting of O₂, H₂, F₂, N₂, ~~dilute gas~~noble gas or rare gas, halide gas, and mixtures thereof.